

L Number	Hits	Search Text	DB	Time stamp
2	1	("4593302").PN.) and (polysilicon with gate)	USPAT; US-PGPUB	2001/12/29 11:56
3	15691	"P" with type with gate	USPAT; US-PGPUB	2001/12/29 11:57
4	5676	("P" with type with gate) and (polysilicon with gate)	USPAT; US-PGPUB	2001/12/29 11:57
5	3075	((("P" with type with gate) and (polysilicon with gate)) and boron	USPAT; US-PGPUB	2001/12/29 11:58
6	2906	((("P" with type with gate) and (polysilicon with gate)) and boron) and (gate with oxide)	USPAT; US-PGPUB	2001/12/29 11:58
7	2705	((("P" with type with gate) and (polysilicon with gate)) and boron) and (gate with oxide)) and channel	USPAT; US-PGPUB	2001/12/29 11:59
8	1197	(((("P" with type with gate) and (polysilicon with gate)) and boron) and (gate with oxide)) and channel) and mosfet	USPAT; US-PGPUB	2001/12/29 12:04
9	266	(((("P" with type with gate) and (polysilicon with gate)) and boron) and (gate with oxide)) and channel) and mosfet) and ((implant\$3 dop\$4) with polysilicon with boron)	USPAT; US-PGPUB	2001/12/29 12:16
10	495	"P" adj type adj gate	USPAT; US-PGPUB	2001/12/29 12:19
11	116	"P" adj type adj polysilicon adj gate	USPAT; US-PGPUB	2001/12/29 12:20